NSN 5961-00-173-1160

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View Online at https://aerobasegroup.com/nsn/5961-00-173-1160 **Inclosure Material:** Metal **Overall Length:** 0.223 inches **Overall Height:** 0.165 inches **Overall Width:** 0.375 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: